2SC2853, 2SC2854

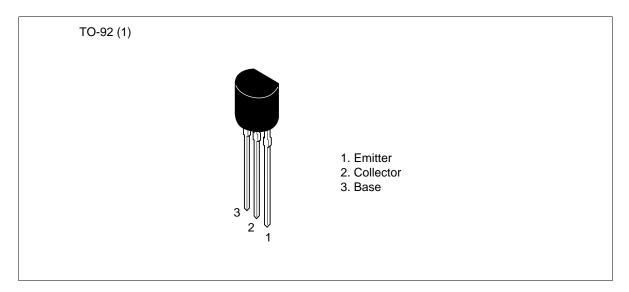
Silicon NPN Epitaxial

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Application

- Low frequency amplifier
- Complementary pair with 2SA1188 and 2SA1189

Outline





2SC2853, 2SC2854

Absolute Maximum Ratings ($Ta = 25^{\circ}C$)

Item	Symbol	2SC2853	2SC2854	Unit
Collector to base voltage	V _{CBO}	90	120	V
Collector to emitter voltage	V _{CEO}	90	120	V
Emitter to base voltage	V _{EBO}	5	5	V
Collector current	I _c	100	100	mA
Emitter current	I _E	-100	-100	mA
Collector power dissipation	Pc	400	400	mW
Junction temperature	Тј	150	150	°C
Storage temperature	Tstg	-55 to +150	–55 to +150	°C

Electrical Characteristics (Ta = 25°C)

		2SC2853		2SC2854					
Item	Symbol	Min	Тур	Max	Min	Тур	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(\text{BR})\text{CBO}}$	90	_	_	120	_	_	V	$I_{c} = 10 \ \mu A, I_{E} = 0$
Collector to emitter breakdown voltage	$V_{(\text{BR})\text{CEO}}$	90	—	_	120	—	—	V	I_{c} = 1 mA, R_{BE} = ∞
Emitter to base breakdown voltage	$V_{(BR)EBO}$	5	_	_	5	_	_	V	$I_{\rm E} = 10 \ \mu A, \ I_{\rm C} = 0$
Collector cutoff current	I _{CBO}	_		0.1		—	0.1	μΑ	$V_{\rm CB} = 70 \ V, \ I_{\rm E} = 0$
Emitter cutoff current	I _{EBO}	_		0.1		—	0.1	μΑ	$V_{EB} = 2 V, I_{C} = 0$
DC current transfer ratio	h_{FE}^{*1}	250	—	800	250	—	800		$V_{ce} = 12 \text{ V}, \text{ I}_{c} = 2 \text{ mA}^{*2}$
Collector to emitter saturation voltage	$V_{\text{CE(sat)}}$	_	0.05	0.10	—	0.05	0.10	V	$I_{c} = 10 \text{ mA}, I_{B} = 1 \text{ mA}^{*2}$
Base to emitter saturation voltage	$V_{\text{BE(sat)}}$	_	0.7	1.0	_	0.7	1.0	V	-
Gain bandwidth product	f _T	_	310	_		310	_	MHz	$V_{ce} = 6 \text{ V}, I_c = 10 \text{ mA}$
Collector output capacitance	Cob	_	3	_	_	3	_	pF	$V_{CB} = 10 \text{ V}, \text{ I}_{E} = 0,$ f = 1 MHz

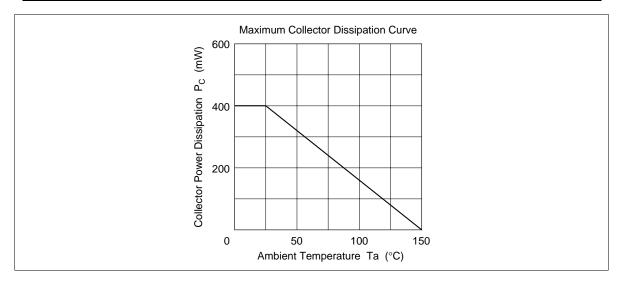
SC2853 and 2SC2854 are grouped by h_{FE} as follows. otes:

2.	2. Pulse test			
D	E			
250 to 500	400 to 800			

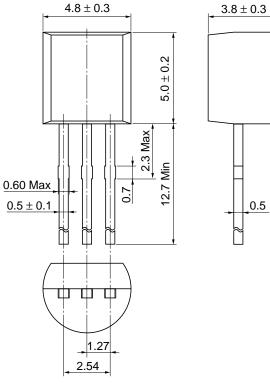
See characteristic curves of 2SC2855 and 2SC2856.

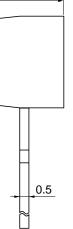
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2SC2853, 2SC2854



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Weight (reference value) 0.25 g

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